



25L6, 25L6-GT/G

BEAM POWER AMPLIFIER

Heater Coated Unipotential Cathode			
Voltage 25 a-c or d-c volts			
Current	0.3	a-c or u-c	amp.
our rent	2516	25L6-GT/G	anp.
Direct Interelectrode Cap.	<u> </u>	A A	-
Grid to Plate	0.3	0.8	μμf
Input	16.0	15	μμf
Output	13.5	10	μμf
Maximum Overall Length	3-1/4"	3-5/16"	μμ.
Maximum Seated Height	2-11/16"	2-3/4"	
Maximum Diameter	1-5/16"	1-5/16"	
Bulb Metal	Shell, MT-8	T-9	
1	Small Wafer	[Intermed. Sh	
	Octal 7-Pin	1 Octal 7-Pin	
Basing Designation	7AC	G-7AC	
25L6, Shell	@ @	Pin 5-Grid	
		Pin 7 - Heate	r
Pin 2-Heater Pin 8-Cathode,			
Pin 3-Plate ②	777 (7)		d #3
. Pin 4 - Screen	0.0		
Mounting Position	TOLL LA CH		Any
BOTTOM VIEW			
Maximum Ratings Are Design-Center Values			
AMPLIFIER .			
Plate Voltage		200 max.	volts
Screen Voltage			volts
Plate Dissipation			watts
Screen Dissipation			watts
Typical Operation and Characteristics - Class A, Amplifier:			
Plate Voltage	100		volts
Screen Voltage	110		voits
Grid Voltage*	-7.5		volts
Peak A-F Grid Voltage	7.5	•	volts
Zero-Sig. Plate Cur.	49	- 50 r	na.
MaxSig. Plate Cur.	50		na.
Zero-Sig. Screen Cur.	4	2 approx.	na.
Max. Sig. Screen Cur.	11	7 approx. ma.	
Plate Resistance	13000	30000 approx.	ohms
Transconductance	9000		umhos
Load Resistance	2000	3000	ohms
Total Harmonic Dist.	10	10	%
_ Max.—Sig. Power Output	2.1	4.3	watts
In circuits where the cathode is not directly connected to the heater, the potential difference between heater and cathode should be kept as			
With shell connected to cathode. Values are approximate.			
* The type of input coupling used should not introduce too much realest.			
ance in the grid circuit. Transformer- or impedance-coupled devices			
are recommended. When the gri than 0.1 megohm. fixed bise ma	d circuit has i	a resistance not	higher
* With shell connected to cathode. Values are approximate. * With no external shield. Values are approximate. * The type of input coupling used should not introduce too much resistance in the grid circuit. Transformer— or impedance—coupled devices are recommended. when the grid circuit has a resistance not higher than 0.1 megohm, fixed bias may be used; for higher values, cathode bias is required. With cathode bias, the grid circuit may have a resistance not to exceed 0.5 megohm.			
Sistance not to exceed 0.5 mego	nm.		i

Mar. 20, 1943

← Indicates a change.

Curves under Type 50L6-GT apply to the 25L6 and 25L6-GT/G.



AVERAGE PLATE CHARACTERISTICS TRIODE CONNECTION

